## NSN 5962-01-364-2000

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| Operating Tempurature Range:  |
|---|
| -55.0/+125.0 degrees celsius  |
| Storage Tempurature Range:  |
| -65.0/+150.0 degrees celsius  |
| End Application:  |
| Display conso e/i fscm 49956  |
| Features Provided:  |
| Programmed  |
| Inclosure Material:   |
| Ceramic   |
| Inclosure Configuration:  |
| Dual-in-line  |
| Output Logic Form:  |
| Bipolar metal-oxide semiconductor   |
| Case Outline Source And Designator:   |
| D-2 mil-m-38510   |
| Terminal Surface Treatment:   |
| Solder  |
| Product Name:   |
| Bipolar prom  |
| Voltage Rating And Type Per Characteristic:   |
| 5.5 volts absolute input and 7.0 volts absolute input   |
| Memory Device Type:   |
| Prom  |
| Test Data Document:   |
| 49956-979735-108 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, |
| etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)                     |
| Terminal Type And Quantity:   |
| 16 printed circuit  |
| Specification Data:   |
| 96906-mil-std-883/tx/ government standard   |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
| <del>-</del>  |
| Demilitarization:   |
| Yes - demil/mli   |
| Fiig:   |
| A458a0  |
|   |